Unit

mW °C

°C

MAZW000H Series

Silicon planar type

For surge absorption circuit

Features

• Two elements anode-common type

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Note) *: Ptot = 150 mW achieved with a printed circuit board.

Symbol

Ptot

Ti

T_{stg}

Rating 150

 $\frac{150}{-55 \text{ to } +150}$

• SSS-Mini type 3-pin package

Parameter

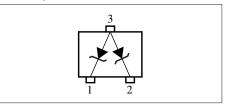
Total power dissipation *

Junction temperature

Storage temperature

0.00+0.05	Unit: mm
0.33 ^{+0.05}	0.10+0.05
	0.15 min.
(0.40) 0.80±0.05 1.20±0.05	0.15 min
5*	
	00 15 max 10 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0
	1: Cathode 1
	2: Cathode 2 3: Anode 1, 2
	SSSMini3-F1 Package

Internally connected circuit



Common Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol		Conditions	Min	Тур	Max	Unit	
Zener voltage *	VZ	IZ	Specified value					V
Zener rise operating resistance	R _{ZK}	IZ	Specified value	Refer to the list of the electrical characteristics – within part numbers				Ω
Zener operating resistance	R _Z	IZ	Specified value					
Reverse current	I _R	V _R	Specified value					μΑ

Note) 1. Measuring methods are based JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. Electrostatic breakdown voltage is $\pm 10 \text{ kV}$

Test method: IEC1000-4-2 (C = 150 pF, R = 330 Ω , Contact discharge: 10 times)

3. *: The temperature must be controlled 25°C for V_{Z} mesurement.

 V_Z value measured at other temperature must be adjusted to $V_Z\,(25^\circ C)$

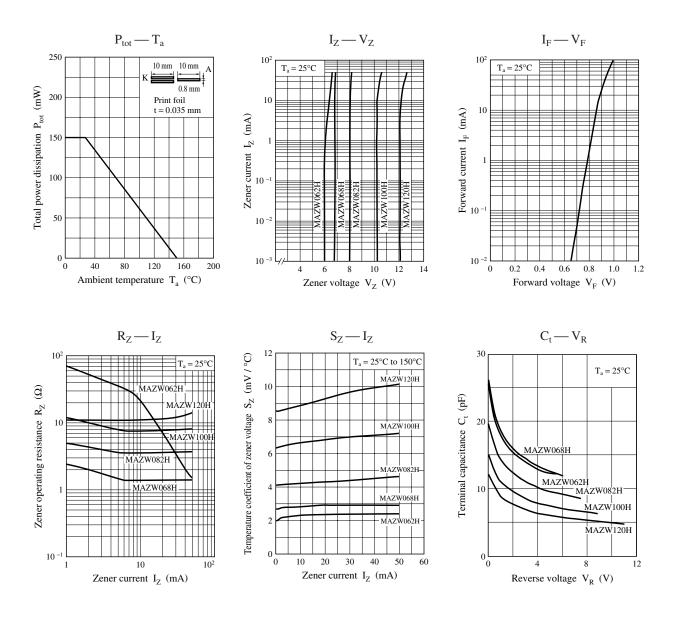
 $V_{\rm Z}$ guaranted 20 ms after current flow.

	Zener voltage				Reverse current (DC)		Zener operating resistance		
Part number	V _Z (V) Ι _R (μΑ			R _Z (Ω) R		Marking symbol			
	Min	Nom	Max	I _Z (mA)	Max	V _R (V)	I _Z = 5 mA Max	l _z = 0.5 mA Max	
MAZW062H	5.8	6.2	6.6	5	0.2	4	50	100	62
MAZW068H	6.4	6.8	7.2	5	0.1	4	30	60	68
MAZW082H	7.7	8.2	8.7	5	0.1	5	30	60	82
MAZW100H	9.4	10.0	10.6	5	0.05	7	30	60	10
MAZW120H	11.4	12.0	12.7	5	0.05	9	30	60	12

Electrical characteristics within part numbers $T_a = 25^{\circ}C \pm 3^{\circ}C$

Note) 1. The V_Z value is the one after power application for 20 ms at $T_a = 25^{\circ}C$.

2. The zener voltage temperature coefficient is the one for T_j = 25°C to 150°C.



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